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Tailoring bandgap and trap distribution via Si or Ge substitution for Sn to improve mechanoluminescence in $Sr_3Sn_2O_7:Sm^{3+}$ layered perovskite oxide

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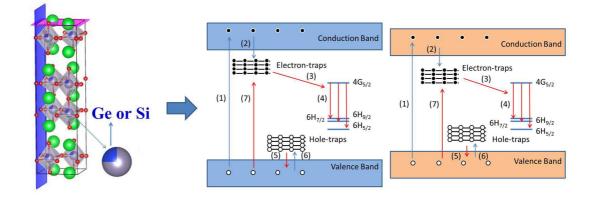
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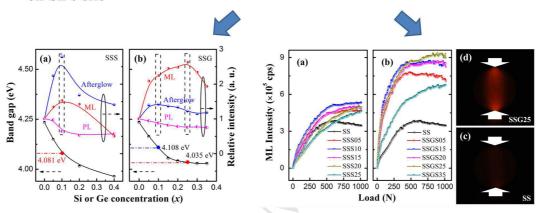






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Bandgap and trap distribution



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